

Vishay General Semiconductor

# **TRANSZORB®** Transient Voltage Suppressors



PRIMARY CHARACTERISTICS				
V <sub>WM</sub>	5.0 V to 18 V			
P <sub>PPM</sub>	1500 W			
PD	6.5 W			
I <sub>FSM</sub>	200 A			
T <sub>J</sub> max.	175 °C			

## **DEVICES FOR BI-DIRECTION APPLICATIONS**

For bi-directional types, use C suffix (e.g. ICTE-18C). Electrical characteristics apply in both directions.

# FEATURES

- Glass passivated chip junction
- Available in uni-directional and bi-directional
- 1500 W peak pulse power capability with a ( 10/1000 μs waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- · Very fast response time
- Low incremental surge resistance
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial and telecommunication.

## **MECHANICAL DATA**

**Case:** Molded epoxy body over passivated junction Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, high reliability/ automotive grade (AEC Q101 qualified)

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

**Polarity:** For uni-directional types the color band denotes cathode end, no marking on bi-directional types

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \degree C$ unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Peak pulse power dissipation with a 10/1000 $\mu$ s waveform <sup>(1)</sup> (Fig. 1)	P <sub>PPM</sub>	1500	W			
Peak pulse current with a 10/1000 $\mu$ s waveform <sup>(1)</sup> (Fig. 3)	I <sub>PPM</sub>	See next table	А			
Power dissipation on infinite heatsink at $T_L = 75 \ ^\circ C$ (Fig. 8)	P <sub>D</sub>	6.5	W			
Peak forward surge current 8.3 ms single half sine-wave uni-directional only <sup>(2)</sup>	I <sub>FSM</sub>	200	А			
Maximum instantaneous forward voltage at 100 A for uni-directional only	V <sub>F</sub>	3.5	V			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175	°C			

#### Notes:

(1) Non-repetitive current pulse, per Fig. 3 and derated above  $T_{A}$  = 25  $^{\circ}C$  per Fig. 2

(2) 8.3 ms single half sine-wave, duty cycle = 4 pulses per minute maximum

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<b>ELECTRICAL CHARACTERISTICS (JEDEC REGISTERED DATA)</b> ( $T_A = 25$ °C unless otherwise noted)								
JEDEC TYPE NUMBER	GENERAL SEMICONDUCTOR PART NUMBER	STAND-OFF VOLTAGE V <sub>WM</sub> (V)	MINIMUM <sup>(3)</sup> BREAKDOWN VOLTAGE AT 1.0 mA V <sub>BR</sub> (V)	MAXIMUM REVERSE LEAKAGE AT V <sub>WM</sub> Ι <sub>D</sub> (μΑ)	$\label{eq:maximum} \begin{array}{c} \mbox{MAXIMUM}\\ \mbox{CLAMPING}\\ \mbox{VOLTAGE}\\ \mbox{AT }_{IPP} = 1.0 \mbox{ A}\\ \mbox{V}_{C} \mbox{ (V)} \end{array}$	$\begin{array}{l} \text{MAXIMUM} \\ \text{CLAMPING} \\ \text{VOLTAGE AT} \\ \text{I}_{\text{PP}} = 10 \text{ A} \\ \text{V}_{\text{C}} (\text{V}) \end{array}$	MAXIMUM PEAK PULSE CURRENT I <sub>PP</sub> (A)	
UNI-DIRECT	UNI-DIRECTIONAL TYPES							
1N6373 <sup>(2)</sup>	ICTE-5 <sup>(2)</sup>	5.0	6.0	300	7.1	7.5	160	
1N6374	ICTE-8	8.0	9.4	25.0	11.3	11.5	100	
1N6375	ICTE-10	10.0	11.7	2.0	13.7	14.1	90	
1N6376	ICTE-12	12.0	14.1	2.0	16.1	16.5	70	
1N6377	ICTE-15	15.0	17.6	2.0	20.1	20.6	60	
1N6378	ICTE-18	18.0	21.2	2.0	24.2	25.2	50	
BI-DIRECTIC	BI-DIRECTIONAL TYPES							
1N6382	ICTE-8C	8.0	9.4	50.0	11.4	11.6	100	
1N6383	ICTE-10C	10.0	11.7	2.0	14.1	14.5	90	
1N6384	ICTE-12C	12.0	14.1	2.0	16.7	17.1	70	
1N6385	ICTE-15C	15.0	17.6	2.0	20.8	21.4	60	
1N6386	ICTE-18C	18.0	21.2	2.0	24.8	25.5	50	

#### Notes:

(1) "C" Suffix indicates bi-directional

(2) ICTE-5 and 1N6373 are not available as bi-directional

(3) The minimum breakdown voltage as shown takes into consideration the ± 1 V tolerance normally specified for power supply regulation on most integrated circuit manufacturers data sheets. Please consult factory for devices that require reduced clamping voltages where tighter regulated power supply voltages are employed

(4) Clamping factor: 1.33 at full rated power; 1.20 at 50 % rated power; Clamping factor: the ratio of the actual  $V_C$  (Clamping Voltage) to the  $V_{BR}$  (Breakdown Voltage) as measured on a specific device

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ICTE-5-E3/54	0.968	54	1400	13" diameter paper tape and reel		
ICTE-5HE3/54 (1)	0.968	54	1400	13" diameter paper tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified



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# **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

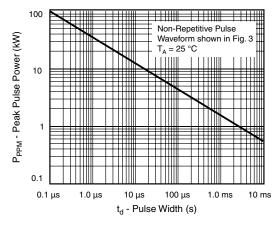


Figure 1. Peak Pulse Power Rating Curve

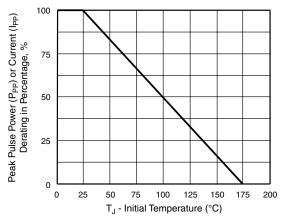


Figure 2. Pulse Power or Current vs. Initial Junction Temperature

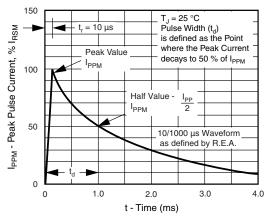


Figure 3. Pulse Waveform

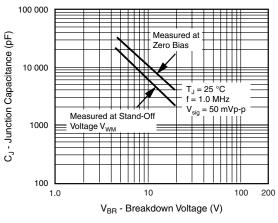


Figure 4. Typical Junction Capacitance Uni-Directional

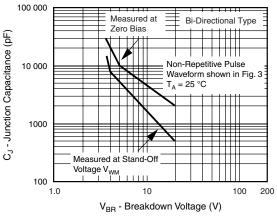
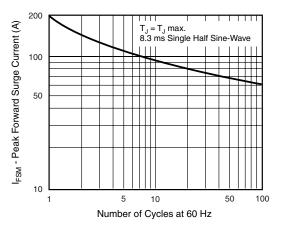
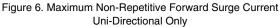


Figure 5. Typical Junction Capacitance

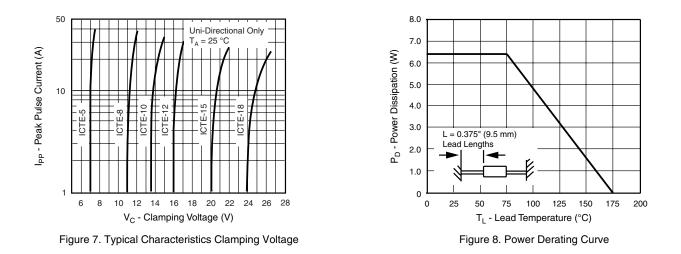




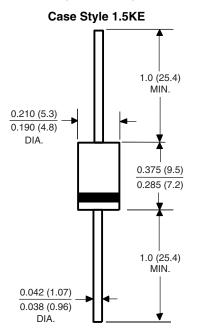
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# ICTE5.0 thru ICTE18C, 1N6373 thru 1N6386

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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







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